

MA2D760A

Silicon epitaxial planer type

For switching power supply

■ Features

- TO-220D package
- $I_{F(AV)}= 5A$ rectification possible
- $V_R= 100V$ guaranteed
- Single type

■ Absolute Maximum Ratings (Ta= 25°C)

Parameter	Symbol	Rating	Unit
Repetitive peak reverse voltage	V_{RRM}	100	V
Average forward current	$I_{F(AV)}$	5	A
Non-repetitive peak forward surge current	I_{FSM}^*	90	A
Junction temperature	T_j	− 40 to +125	°C
Storage temperature	T_{stg}	− 40 to +125	°C

* 50Hz sine wave, one-cycle wave, high value (non-repetitive)

■ Electrical Characteristics (Ta= 25°C)

Parameter	Symbol	Condition	min	typ	max	Unit
Reverse current (DC)	I_R	$V_R=100V, T_C= 25^{\circ}C$			3	mA
Forward voltage (DC)	V_F	$I_F= 5A, T_C= 25^{\circ}C$			0.85	V
Thermal resistance	$R_{th(j-c)}$				3.0	°C/W

- Note
1. Test method : According to JIS C7031 "Testing Methods for Small Signal Diodes"
 2. Rated input/output frequency : 150kHz
 3. Tightening torque-max. 8kg/cm

